Ordering number : ENA1477



ON Semiconductor DATA SHEET

N-Channel Silicon MOSFET

EFC4612R — General-Purpose Switching Device Applications

Features

- 2.5V drive.
- · Built-in gate protection resistor.
- · Best suited for LiB charging and discharging switch.
- · Common-drain type.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Source-to-Source Voltage	VSSS		24	V
Gate-to-Source Voltage	V _{GSS}		±12	V
Source Current (DC)	IS		6	Α
Source Current (Pulse)	ISP	PW≤10μs, duty cycle≤1%	60	А
Total Dissipation	PT	When mounted on ceramic substrate (5000mm ² ×0.8mm)	1.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions		Ratings			Unit
				min	typ	max	Unit
Source-to-Source Breakdown Voltage	V(BR)SSS	I _S =1mA, V _{GS} =0V	Test Circuit 1	24			V
Zero-Gate Voltage Source Current	ISSS	Vss=20V, Vgs=0V	Test Circuit 1			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±8V, VSS=0V	Test Circuit 2			±10	μΑ
Cutoff Voltage	VGS(off)	VSS=10V, IS=1mA	Test Circuit 3	0.5		1.3	V
Forward Transfer Admittance	yfs	Vss=10V, Is=3A	Test Circuit 4		3.1		S

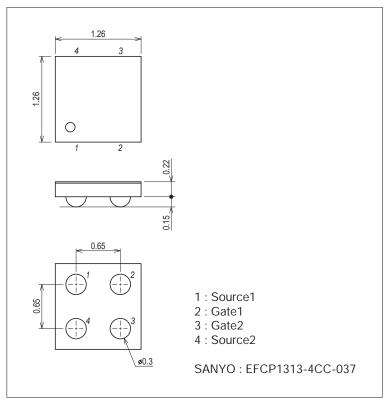
Marking: FN Continued on next page.

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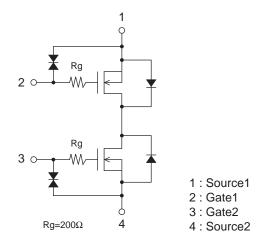
Parameter	Cumbal	Conditions		Ratings			Linit
	Symbol Condition			min	typ	max	Unit
Static Source-to-Source On-State Resistance	R _{SS} (on)1	I _S =3A, V _{GS} =4.5V	Test Circuit 5	24	39	45	mΩ
	RSS(on)2	IS=3A, VGS=4.0V	Test Circuit 5	25	41	48	mΩ
	RSS(on)3	IS=3A, VGS=3.7V	Test Circuit 5	27.5	43	50	mΩ
	R _{SS} (on)4	I _S =3A, V _{GS} =3.1V	Test Circuit 5	31.5	48	57	mΩ
	RSS(on)5	I _S =3A, V _{GS} =2.5V	Test Circuit 5	33.5	58	72	mΩ
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.	Test Circuit 7		20		ns
Rise Time	tr	See specified Test Circuit.	Test Circuit 7		230		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.	Test Circuit 7		130		ns
Fall Time	tf	See specified Test Circuit.	Test Circuit 7		210		ns
Total Gate Charge	Qg	V _S S=10V, V _G S=4.5V, I _S =6A			7		nC
Forward Source-to-Source Voltage	VF(S-S)	IS=3A, VGS=0V	Test Circuit 6		0.8	1.2	V

Package Dimensions

unit : mm (typ) 7064-001



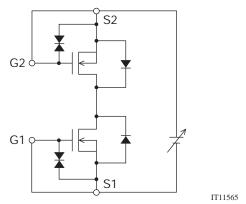
Electrical Connection



Test circuits are example of measuring FET1 side

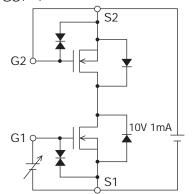
Test Circuit 1

VSSS / ISSS



Test Circuit 3

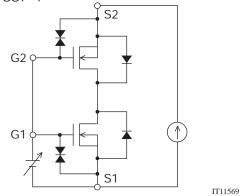
V_GS(off)



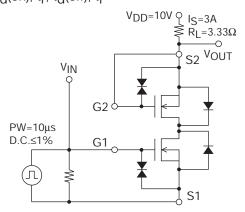
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Test Circuit 5

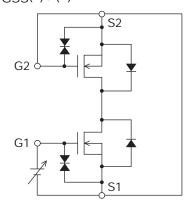
Rss(on)



Test Circuit 7 $t_d(on)$, t_r , $t_d(off)$, t_f



Test Circuit 2 IGSS(+) / (--)

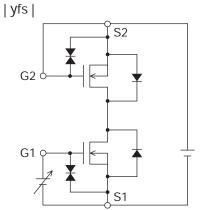


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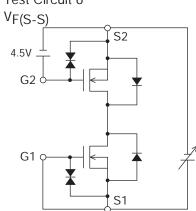
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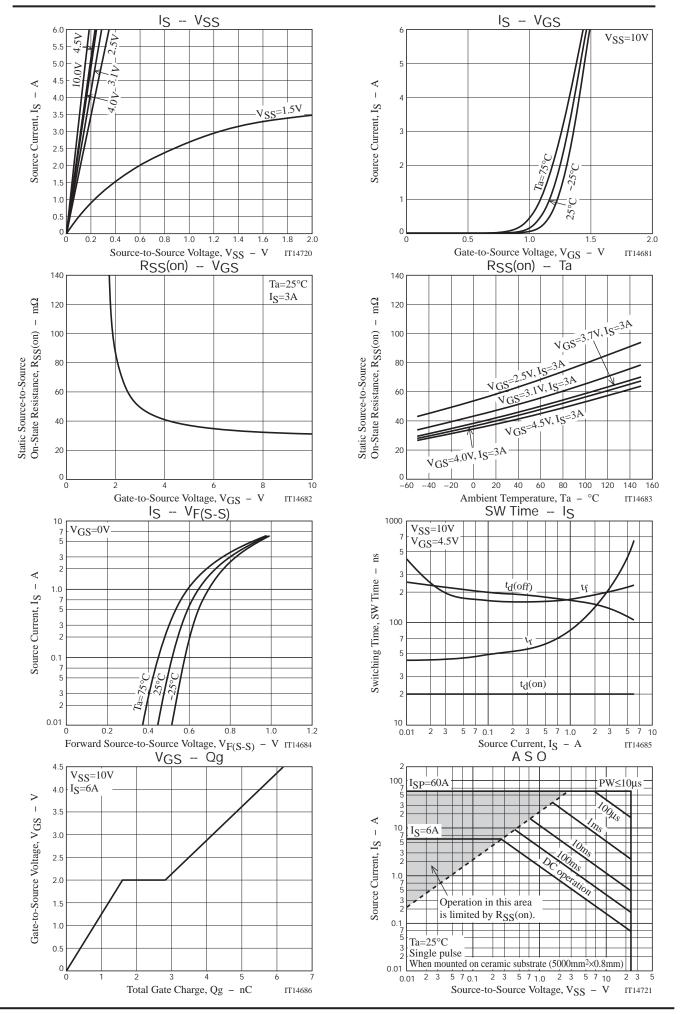
Test Circuit 4

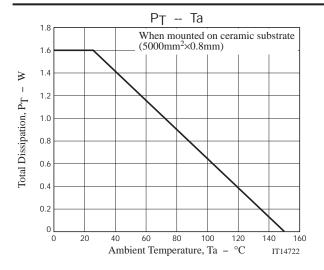


Test Circuit 6



* Note: Connect the mesurement terminal reversely if you want to measure the FET2 side.





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